

Title (en)
RADIO FREQUENCY POWER AMPLIFIER WITH LINEARIZING PREDISTORTER

Title (de)
HOCHFREQUENZ-LEISTUNGSVERSTÄRKER MIT LINEARISIERUNGSVORVERZERRER

Title (fr)
AMPLIFICATEUR DE PUISSANCE RADIOFRÉQUENCE COMPRENANT UN COMPOSANT DE PRÉDISTORSION DE LINÉARISATION

Publication
EP 2467943 A1 20120627 (EN)

Application
EP 09848548 A 20090817

Priority
US 2009054023 W 20090817

Abstract (en)
[origin: WO2011021995A1] A power amplifier circuit includes an amplifier MOSFET and a predistorter MOSFET. The predistorter MOSFET source and drain are connected together, and the predistorter MOSFET is connected between the gate of the amplifier MOSFET and a second bias voltage signal. This biasing of the predistorter MOSFET causes it to provide a nonlinear capacitance at the gate of the amplifier MOSFET. The combined non-linear capacitances of the amplifier MOSFET and predistorter MOSFET provide predistortion that promotes cancellation of the distortion or nonlinearity contributed by the amplifier MOSFET alone.

IPC 8 full level
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H03F 3/04 (2013.01 - KR); **H03F 3/082** (2013.01 - KR); **H03F 3/189** (2013.01 - KR); **H03F 3/19** (2013.01 - KR); **H03F 3/193** (2013.01 - EP);
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